Diode Semiconductor Device - Page 1 of 1



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	ure Material:
Glass	
Overal	I Length:
0.160 ii	nches
Termin	nal Length:
1.250 ii	nches
Overal	I Diameter:
0.075 ii	nches
Function	on For Which Designed:
Zener o	diode
Joint E	Electronic Device Engineering Council/jedec/case Outline Designation
Do-204	lah
Mounti	ing Method:
Termin	al
Featur	es Provided:
Hermet	tically sealed case
Semico	onductor Material:
Silicon	
Voltage	e Rating In Volts Per Characteristic:
4.3 re	gulator voltage
Voltage	e Tolerance In Percent:
-5.0/+5	.0
Curren	t Rating Per Characteristic:
20.00 n	nilliamperes all primaries horsepower metric
Power	Rating Per Characteristic:
500.0 n	nilliwatts small-signal input power, common-collector absolute
Maxim	um Operating Tempurature Per Measurement Point:
200.0 c	degrees celsius ambient air
Termin	nal Type And Quantity:
2 unins	ulated wire lead
Specifi	ication Data:
80131-	release5566 professional/industrial association specification
Shelf L	.ife:
N/a	
Unit Of	f Measure:
Demilit	tarization:
No	
Fiig:	
A110a0)